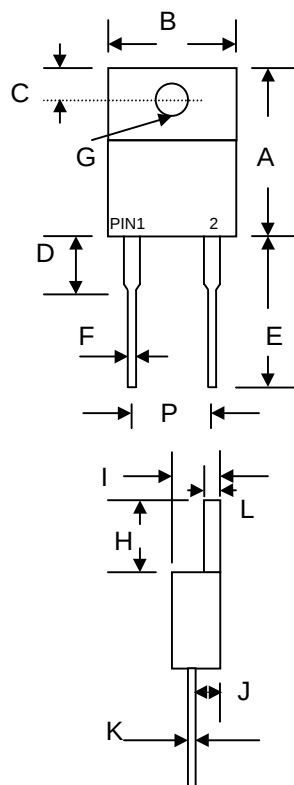


Features

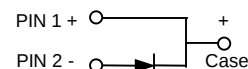
- Glass Passivated Die Construction
- Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 2.24 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



TO-220A		
Dim	Min	Max
A	14.9	15.1
B	—	10.5
C	2.62	2.87
D	3.56	4.06
E	13.46	14.22
F	0.68	0.94
G	3.74 Ø	3.91 Ø
H	5.84	6.86
I	4.44	4.70
J	2.54	2.79
K	0.35	0.64
L	1.14	1.40
P	4.95	5.20
All Dimensions in mm		



Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

Characteristic	Symbol	FR 1601G	FR 1602G	FR 1603G	FR 1604G	FR 1605G	FR 1606G	FR 1607G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current @T _C = 105°C	Io	16							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	250							A
Forward Voltage @IF = 16A	VFM	1.3							V
Peak Reverse Current @TA = 25°C At Rated DC Blocking Voltage @TA = 125°C	IRM	5.0 100							µA
Reverse Recovery Time (Note 1)	trr	150				250	500		nS
Typical Thermal Resistance Junction to Case	RθJC	3.0							K/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150							°C

Note: 1. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A. See figure 5.

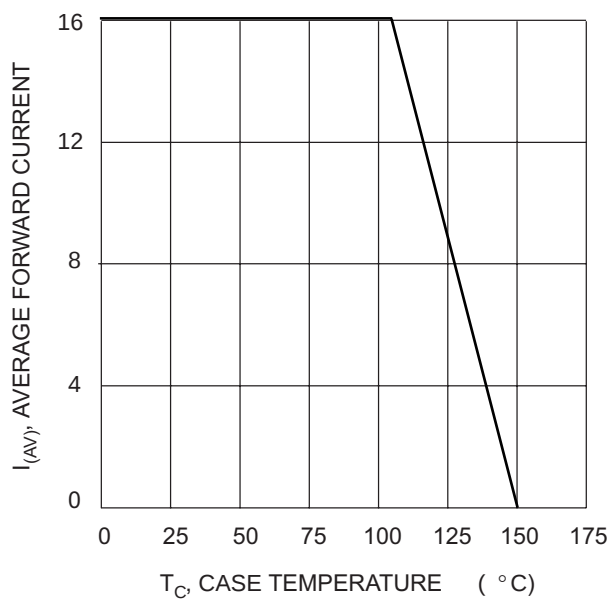


Fig. 1, Typical Forward Current Derating Curve

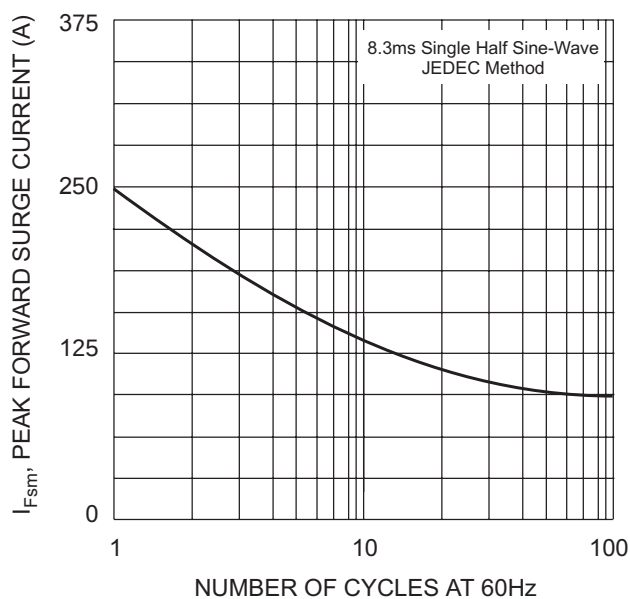


Fig. 2 Max Non-Repetitive Peak Surge Current

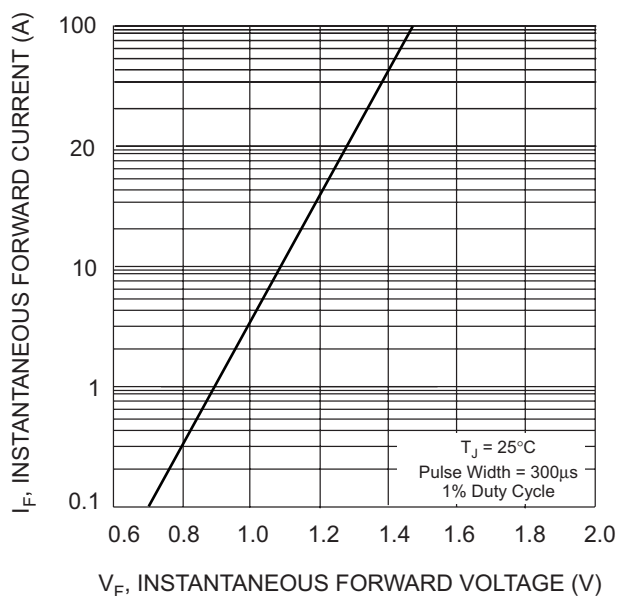


Fig. 3, Typical Instantaneous Forward Characteristics

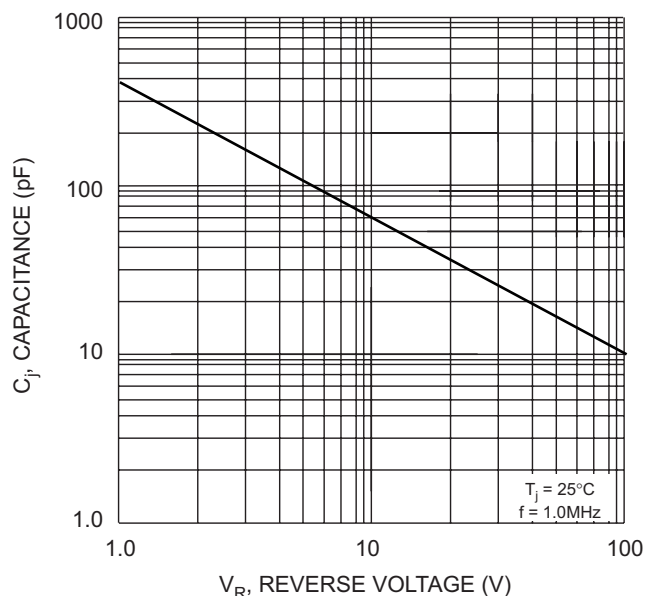
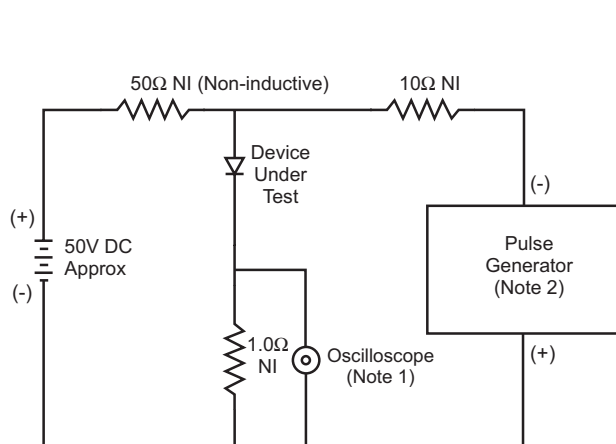


Fig. 4 Typical Junction Capacitance



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.

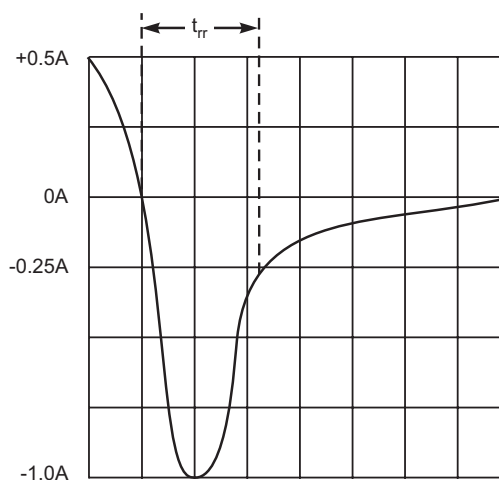


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit